

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	)	
	)	
Seok-Woo LEE	)	
	)	
Application No.: Unassigned	)	Group Art Unit: Unassigned
	)	
Filed: August 27, 2003	)	Examiner: Unassigned
	)	

For: METHOD OF FABRICATING TOP GATE TYPE THIN FILM  
TRANSISTOR HAVING LOW TEMPERATURE POLYSILICON

Commissioner for Patents  
**MAIL STOP PATENT APPLICATION**

**INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)**

Pursuant to 37 C.F.R. §§ 1.56 and 1.97(b), Applicant brings to the attention of the Examiner the documents listed on the attached PTO-1449. This Information Disclosure Statement is being filed within three months of the filing date of the above-referenced application.

A copy of each listed document is attached.

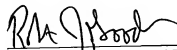
An English language abstract, submitted herewith, constitutes a concise statement of relevance for Korean Patent No. 0154765.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that the listed document is material or constitutes "prior art." If it should be determined that the listed document does not constitute "prior art" under United States law, Applicants reserve the right to present to the Office the relevant facts and law regarding the appropriate status of such document. Applicants further reserve the right to take appropriate action to establish the patentability of the disclosed invention over the listed document, should the document be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 50-0310.

Respectfully submitted,

**MORGAN, LEWIS & BOCKIUS LLP**

A handwritten signature in black ink, appearing to read 'R. J. Goodell', written over a horizontal line.

Robert J. Goodell, Reg. No. 41,040

Date: August 27, 2003

**MORGAN, LEWIS & BOCKIUS LLP**  
1111 Pennsylvania Avenue, N.W.  
Washington, D.C. 20004  
(202) 739-3000

